Excellent Integrated System Limited

Stocking Distributor

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Diodes Incorporated ES3B-13-F

For any questions, you can email us directly: sales@integrated-circuit.com



Distributor of Diodes Incorporated: Excellent Integrated System Limited

Datasheet of ES3B-13-F - DIODE GEN PURP 100V 3A SMC

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ES3A/AB - ES3D/DB

3.0A SURFACE MOUNT SUPER-FAST RECTIFIER

Features

- Glass Passivated Die Construction
- Super-Fast Recovery Time For High Efficiency
- Surge Overload Rating to 100A Peak
- Ideally Suited for Automated Assembly
- Lead Free Finish/RoHS Compliant (Note 1)
- Green Molding Compound (No Halogen and Antimony) (Note 2)

Mechanical Data

- Case: SMB/SMC
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (23)
- Polarity: Cathode Band or Cathode Notch
- SMB Weight: 0.093 grams (approximate)
- SMC Weight: 0.21 grams (approximate)





Top View

Bottom View

Ordering Information (Note 3)

Part Number	Case	Packaging
ES3x-13-F	SMC	3000/Tape & Reel
ES3xB-13-F	SMB	3000/Tape & Reel

^{*} x = Device type, e.g. ES3A-13-F (SMC package); ES3AB-13-F (SMB package).

Notes:

- 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
- 2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



ES3x = Product type marking code, ex: ES3A (SMC package)
ES3xB = Product type marking code, ex: ES3AB (SMB package)

H = Manufacturers' code marking

YWW = Date code marking

Y = Last digit of year (ex: 2 for 2002)

WW = Week code (01 to 53)

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ES3A/AB - ES3D/DB

Maximum Ratings @TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	ES3A/AB	ES3B/BB	ES3C/CB	ES3D/DB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 4)	V _{RRM} V _{RWM} V _R	50	100	150	200	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	V
Average Rectified Output Current @ T _T = 100°C	lo		3	.0		Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load			10	00		Α

Thermal Characteristics

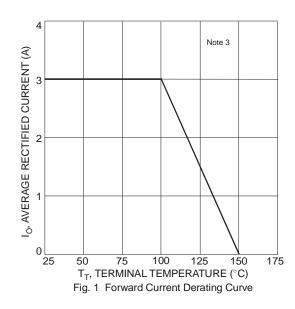
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal	$R_{\theta JT}$	10	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	50	°C
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

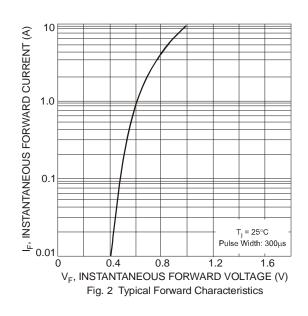
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Maximum Forward Voltage	$@ I_F = 3.0A$	V_{FM}	0.9	V
Peak Reverse Current at Rated DC Blocking Voltage (Note 4)	@ T _A = 25°C @ T _A = 125°C	I _{RM}	10 500	μА
Maximum Reverse Recovery Time (Note 6)		t _{rr}	25	ns
Typical Total Capacitance (Note 7)		C _T	45	pF

Notes:

- 4. Short duration pulse test used to minimize self-heating effect.
- 5. Unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pads as heat sink. 6. Measured with $I_F=0.5A$, $I_R=1.0A$, $I_{rr}=0.25A$. See Figure 5. 7. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

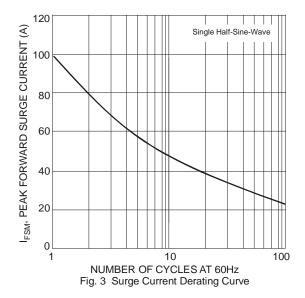






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ES3A/AB - ES3D/DB



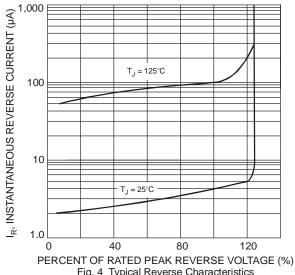
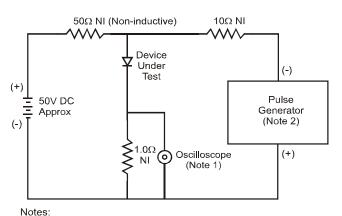
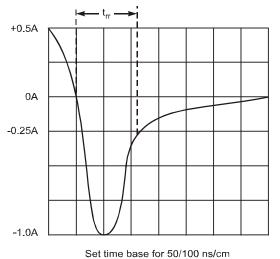


Fig. 4 Typical Reverse Characteristics



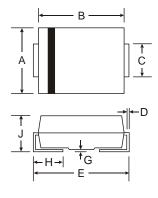


1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF.

2. Rise Time = 10ns max. Input Impedance = 50Ω .

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

Package Outline Dimensions



SMB				
Dim	Min	Max		
Α	3.30	3.94		
В	4.06	4.57		
С	1.96	2.21		
D	0.15	0.31		
Е	5.00	5.59		
G	0.05	0.20		
Н	0.76	1.52		
J	2.00	2.50		
All Dimensions in mm				

SMC				
Dim	Min	Max		
Α	5.59	6.22		
В	6.60	7.11		
C	2.75	3.18		
D	0.15	0.31		
Е	7.75	8.13		
G	0.10	0.20		
Η	0.76	1.52		
7	2.00	2.50		
All Dimensions in mm				

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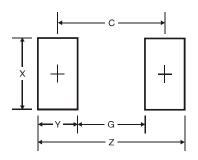
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ES3A/AB - ES3D/DB

Suggested Pad Layout



SMB Dimensions	Value (in mm)
Z	6.7
G	1.8
Х	2.3
Υ	2.5
С	4.3

SMC Dimensions	Value (in mm)
Z	9.3
G	4.4
Х	3.3
Υ	2.5
С	6.8

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